

## GC4902 - GC4946

#### **CONTROL DEVICES – BEAMLEAD PIN DIODES**

RoHS Compliant (e

DESCRIPTION

Semiconductor mesa beam lead PIN diodes are designed for very low inductance, low resistance and moderately low capacitance with ultra fast switching characteristics. The structural details include thermal oxide junction passivation thus providing reliable operation with stable junction parameters along with ceramic glass, which provides mechanical strength to the diode. These devices are designed with a narrow base width, a high quality intrinsic 'l' layer that provides low loss, high isolation and ultra high speed switching characteristics.

This series of diodes meets RoHS requirements per EU Directive 2002/95/EC. The standard terminal finish is gold unless otherwise specified. Consult the factory if you have special requirements.

#### APPLICATIONS

These high speed beam lead PIN diodes are designed for stripline and microstrip circuits and are primarily used in shunt/series and conventional series multithrow configurations as switching, attenuating and phase shifting elements with frequencies extending up to Ku band.

| ABSOLUTE MAXIMUM RATINGS AT 25° C<br>(UNLESS OTHERWISE SPECIFIED) |                  |             |      |  |  |  |  |  |  |
|---|------------------|-------------|------|--|--|--|--|--|--|
| Rating  | Symbol           | Value       | Unit |  |  |  |  |  |  |
| Maximum Leakage Current<br>@80% of minimum Rated V <sub>B</sub>   | I <sub>R</sub>   | 0.5         | uA   |  |  |  |  |  |  |
| Operating Temperature   | T <sub>OP</sub>  | -65 to +150 | °C   |  |  |  |  |  |  |
| Storage Temperature   | T <sub>STG</sub> | -65 to +150 | °C   |  |  |  |  |  |  |

For the most current data, consult MICROSEMI's website: <u>www.MICROSEMI.com</u> Specifications are subject to change, consult factory for the latest information.

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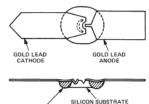
### KEY FEATURES

- Wide Bandwidth / High Switching Speed
- 5 Gram Typical Pull Strength
- Very Low R<sub>S</sub>/C<sub>J</sub> (Loss/Isolation)
  Products with Low Inductance
- High Quality, High Resistivity Epitaxy
- Stable Low Leakage Passivation with Rugged Glass Body
- RoHS Compliant<sup>1</sup>

<sup>1</sup> These devices are supplied with Gold plated terminations. Consult factory for details.

#### **APPLICATIONS/BENEFITS**

- High Speed Switching
- Broadband Performance
- Suitable for Applications through 26 Ghz



CERAMIC REINFORCEMENT

GC4902 - GC4946



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### CONTROL DEVICES – BEAMLEAD PIN DIODES

RoHS Compliant (e4

| ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified) |   |                                      |  |  |                              |  |   |  |  |  |
|---|---|--------------------------------------|--|--|------------------------------|--|---|--|--|--|
|   | DC Characteristics                                  |                                      |  |  | RF Characteristics           |  |   |  |  |  |
| Model Number  | V <sub>b</sub> (V)<br>I <sub>R</sub> =10μΑ<br>(Min) | С <sub>т</sub> (рF)<br>@10∨<br>(Max) | <b>R</b> <sub>s</sub> (Ω)<br>I <sub>F</sub> =10mA<br>F=2.2GHz<br>(Max) | <b>R</b> <sub>s</sub> (Ω)<br>I <sub>F</sub> =50mA<br>F=2.2GHz<br>(Max) | T <sub>∟</sub> (nS)<br>(Typ) | lsol (db) <sup>1</sup><br>∨ <sub>r</sub> =10∨<br>(Typ) | I <sub>L</sub> (db) <sup>1</sup><br>I <sub>F</sub> =10mA<br>(Typ) | l <sub>∟</sub> (db)¹<br><sub>l⊧</sub> =50mA<br>(Typ) |  |  |
| GC4902 – 12   | 100   | 0.025                                |  | 3.0  | 80                           | 29.0   |   | 0.26   |  |  |
| GC4903 – 12   | 100   | 0.030                                |  | 2.5  | 80                           | 27.8   |   | 0.22   |  |  |
| GC4941 – 12   | 50  | 0.060                                | 1.5  |  | 50                           | 22.0   | 0.13  |  |  |  |
| GC4942 – 12   | 50  | 0.040                                | 2.0  |  | 45                           | 25.0   | 0.17  |  |  |  |
| GC4943 – 12   | 50  | 0.030                                | 3.0  |  | 40                           | 27.5   | 0.26  |  |  |  |
| GC4944 – 12   | 50  | 0.025                                | 3.5  |  | 35                           | 29.0   | 0.30  |  |  |  |
| GC4945 – 12   | 50  | 0.022                                | 5.5  |  | 40                           | 30.5   | 0.46  |  |  |  |
| GC4946 – 12   | 50  | 0.020                                | 6.5  |  | 40                           | 31.0   | 0.55  |  |  |  |

#### Notes:

1) Insertion loss and Isolation are test at F = 2.2 GHz using transmission loss techniques.

